

Low-Voltage SPDT Analog Switch, 2:1 Multiplexer / Demultiplexer Bus Switch

Features

- 1.65V to 5.5V Single Supply Operation
- Low ON-State Resistance: 4.5Ω(Typ.)
- -3dB Bandwidth: 300 MHz Typical
- Low Power Consumption
- Fast Switching Speed
- Break-Before-Make Operation
- Rail-to-Rail Operation
- TTL/CMOS Logic Compatible
- Supports Analog and Digital Signals
- Small Packaging: SOT23-6, SC70-6
- Extended Industrial Temperature
 Range: -40°C to +125°C

Applications

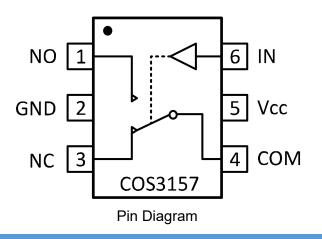
- Multiple-Purpose Signal Switching
- MP3/PDA
- Portable Devices
- Set-Top Box
- Signal Gating, Multiplexer/Demultiplexer
- Signal Modulation or Demodulation
- Sample and Hold Systems
- Telecom Signal Switching
- Battery Power Systems

Rev1.0

General Description

The COSN74LVC1G3157 is a low voltage, high bandwidth single-pole / double-throw (SPDT) CMOS analog switch or 2:1 multiplexer / demultiplexer with single output enable control pin. The device can pass signals with rail-to-rail swing from a single supply 1.65V to 5.5V. The switches conduct equally well in both directions when it is on. The output enable pin place the signal paths in high impedance which isolates the bus when it is not in use and thus consume less current.

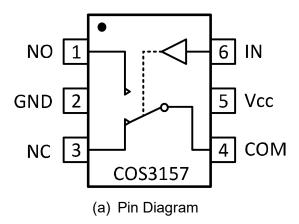
The COSN74LVC1G3157 offers low ON-state resistance and high bandwidth with the break-before- make feature which prevents signal distortion during the transferring of a signal from one channel to another. The device is well suitable for the switching of high-speed signals in handset and consumer applications.

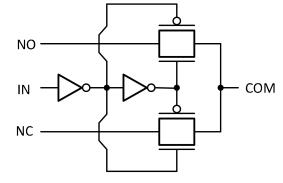


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1. Pin Configuration and Functions





(b) Simplified Schematic

Truth Table

IN	NO	NC
0	OFF	ON
1	ON	OFF

Pin Description

PIN	NAME	FUNCTION		
1	NO	Normally Open Terminal		
2	GND	Ground		
3	NC	Normally Closed Terminal		
4	СОМ	Common Terminal		
5	V _{cc}	Power supply		
6	IN	Digital Control Pin, must be held HIGH or LOW		

2. Package and Ordering Information

Order Number	Package	Package Option	Marking Information
COSN74LVC1G3157DBVR	SOT23-6	Tape and Reel, 3000	C3157
COSN74LVC1G3157DCKR	SC70-6 (SOT363)	Tape and Reel, 3000	C3157



3. Product Specification

3.1 Absolute Maximum Ratings⁽¹⁾

Parameter	Min	Max	Unit
Supply voltage range (V _{cc})	-0.3	6.0	V
Analog voltage range (V _{NC} , V _{NO} , V _{COM})	-0.3	V _{CC} + 0.3	V
Digital input voltage range (V_{IN})	-0.3	6.0	V
Continuous current into any terminal	-50	50	mA
Peak current into any terminal	-80	80	mA
Operating junction temperature	-40	+125	°C
Storage temperature	-55	+150	°C
ESD (HBM)	-2000	+2000	V
ESD (MM)	-400	+400	V

(1) Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

3.2 Thermal Data

Parameter	Rating	Unit
Package Thermal Resistance, $R_{\theta JA}$ (Juntion-to-ambient)	190 (SOT23-6) 270 (SC70-6)	°C/W

3.3 Recommended Operating Conditions

Parameter	Min	Мах	Unit
Vcc	1.65	5.5	
V _{NC} , V _{NO} , V _{COM}	0	Vcc	V
V _{IN}	0	Vcc	
T _A , Operating free-air temperature	-40	+85	°C



3.4 Electrical Characteristics

(Vcc=1.8V to 5.5V, T_A=-40°C to 125°C, Typical values are at Vcc=5.0V, T_A=+25°C, unless otherwise noted)

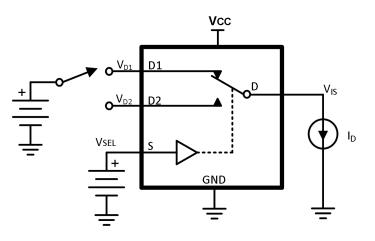
Parameter	Symbol	Conditions	Vcc	TA	Min.	Тур.	Max.	Unit
Analog Switch								
Analog signal range	Vis			FULL	0		Vcc	V
				+25°C		4.5	8	-
On state registeres	P	V_{NO} or $V_{NC} = V_{CC}/2$, $I_{COM} = -10 \text{mA}$,	5V	FULL			8.5	Ω
On-state resistance	R _{ON}	Switch On, See Figure 1	3.3V	+25°C		7	10	Ω
			3.3V	FULL			10.5	12
			5V	+25°C		0.15	0.3	Ω
On-state resistance match	ΔR _{on}	V_{NO} or $V_{NC} = V_{CC}/2$, $I_{COM} = -10 \text{mA}$,	52	FULL			0.4	12
between channels		Switch On, See Figure 1	3.3V	+25°C		0.15	0.3	0
		5	3.3V	FULL			0.4	Ω
		V_{NO} or V_{NC} =0 to $V_{CC}/2$, I_{COM} = -10mA, Switch On, See Figure 1	5V	+25°C		2	3	Ω
	R _{ON} (flat)		50	FULL			3.5	12
On-state resistance flatness			3.3V	+25°C		3	4	Ω
				FULL			4.5	22
OFF-state leakage current	Inc(off) Ino(off)	V_{NO} or V_{NC} = 0.3V, $V_{CC}/2$, $V_{COM} = V_{CC}/2$, 0.3V, Switch OFF, See Figure 2	1.8V to 5.5V	FULL			1	μA
Channel ON leakage current	Inc(on) Ino(on) Icom(on)	V_{NO} or V_{NC} = 0.3V, $V_{CC}/2$, V_{COM} =0.3V, $V_{CC}/2$, Switch ON, See Figure 3	1.8V to 5.5V	FULL			1	μA
Digital Control Input								
Input logic bigh			5V	FULL	2.6			V
Input logic high	VIH		3.3V	FULL	1.7			V
			5V	FULL			0.8	V
Input logic low	VIL		3.3V	FULL			0.7	V
Input leakage current	I _{IH} , I _{IL}	$V_{IN} = 0$ or V_{IO}	1.8V to 5.5V	FULL			1	μA



Switch Dynamic Characte	eristics							
		V_{NC} or $V_{NO} = V_{CC}$,	5V			26		
Turn-on time	t _{on}	$R_L=300\Omega$, $C_L = 35pF$, See Figure 4	3.3V	+25°C		30		ns
- ""	1	V_{NC} or $V_{NO} = V_{CC}$,	5V	.0500		8		ns
Turn-off time	toff	R_L =300 Ω , C_L = 35pF, See Figure 4	3.3V	+25°C ∕		9		
	t _{PHL}	$V_{IS} = 3V,$	5V			1.4		
Propagation delay	t _{PLH}	R_L =300 Ω , C_L = 35pF, See Figure 5	3.3V	+25°C		1.3		ns
		$V_{IS} = 3V$,	5V			5		
Break-before-make delay	t _{ввм}	R_L =300 Ω , C_L = 35pF, See Figure 6	3.3V	+25°C		8		ns
o :		$V_{\text{GEN}} = 0V, R_{\text{GEN}} = 0\Omega,$	5V	0.500		10		_
Charge injection	Q	$C_L = 0.1 nF,$ See Figure 7	3.3V	+25°C		3		рС
OFF-state capacitance	C _{NC(OFF)} C _{NO(OFF)}	$V_{CC} = 3.3V,$ $V_{I/O} = V_{CC}$ or 0, Switch OFF, See Figure 8		+25°C		6		pF
ON-state capacitance	Cnc(on) Cno(on)	$V_{CC} = 3.3V$, $V_{I/O} = V_{CC}$ or 0, Switch ON, See Figure 8		+25°C		15		pF
Digital input capacitance	Cı	$V_{CC} = 0V,$ $V_{IN} = V_{CC} \text{ or } 0,$ See Figure 8		+25°C		2		pF
OFF-isolation	V _{ISO}	$\label{eq:RL} \begin{array}{l} R_{L} = 50\Omega, \ C_{L} = 5pF, \\ V_{I/O} = 0dBm, \ f = 1MHz \\ Switch \ OFF, \\ See \ Figure \ 9 \end{array}$		+25°C		-70		dB
Crosstalk	Xtalk	$\label{eq:RL} \begin{array}{l} R_{L} = 50\Omega, \ C_{L} = 5pF, \\ V_{I/O} = 0dBm, \ f = 1MHz \\ Switch \ ON, \\ See \ Figure \ 10 \end{array}$		+25°C		-72		dB
Bandwidth	BW	$\label{eq:RL} \begin{array}{l} R_L = 50\Omega, \ C_L = 5pF, \\ V_{I/O} = 0dBm, \ f = 1MHz \\ Switch \ ON, \\ See \ Figure \ 11 \end{array}$		+25°C		300		MHz
Power Supply								
V _{CC} supply range	Vcc			FULL	1.65		5.5	V
V _{CC} supply current	Icc	I _{I/O} = 0, Switch ON or OFF	5.5V	FULL			5	μA



4. Test Circuits and Timing Diagrams



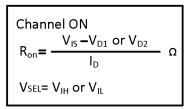


Figure 1. ON-State Resistance (R_{ON})

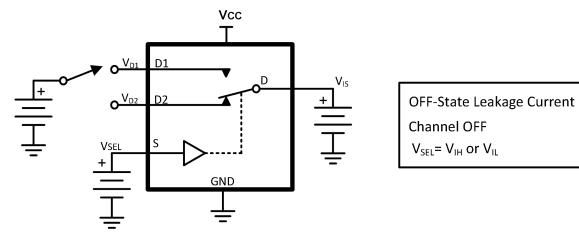
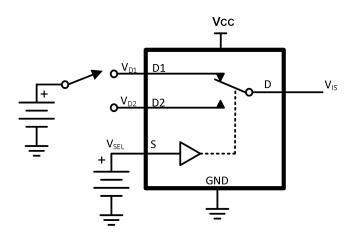


Figure 2. OFF-State Leakage Current



ON-State Leakage Current Channel ON V_{SEL}= V_{IH} or V_{IL}





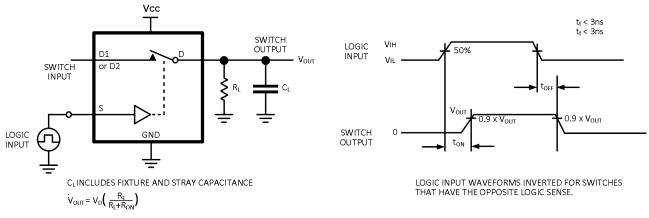
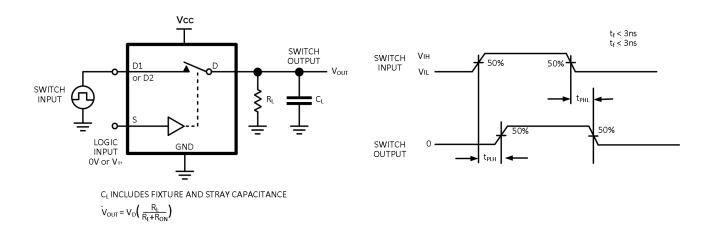


Figure 4. Turn-On (T_{ON}) and Turn-Off Time (T_{OFF})





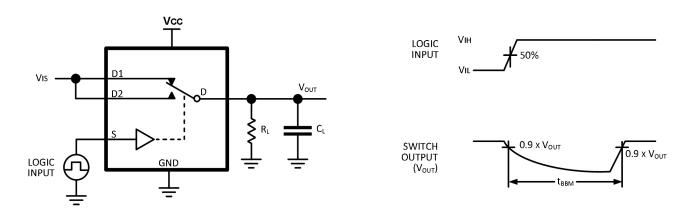
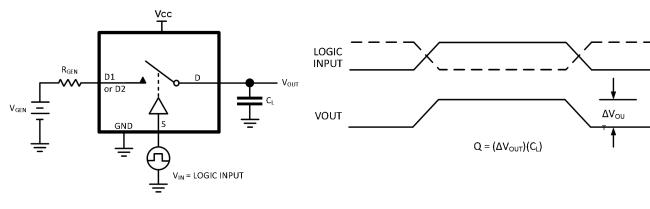
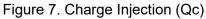
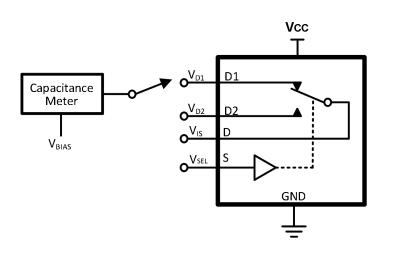


Figure 6. Break-Before-Make Time (T_{BBM})



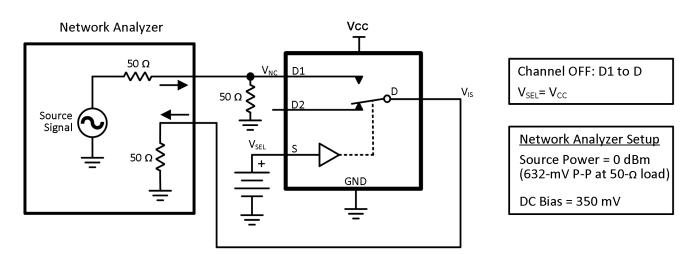






 $V_{BIAS} = V_{CC}$ or GND $V_{SEL} = V_{CC}$ or GND Capacitance is measured at D1, D2, D, and S inputs during ON and OFF conditions.









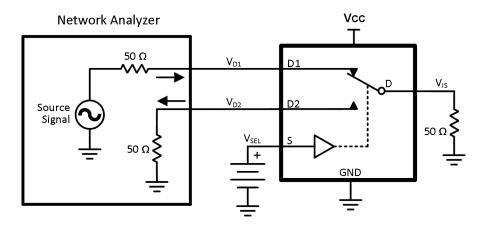
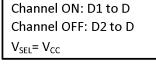


Figure 10. Crosstalk (X_{TALK})



<u>Network Analyzer Setup</u> Source Power = 0 dBm (632-mV P-P at 50-Ω load)

DC Bias = 350 mV

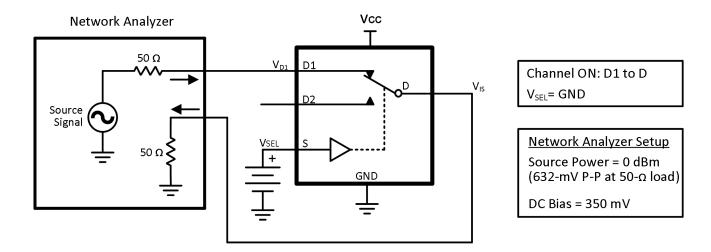


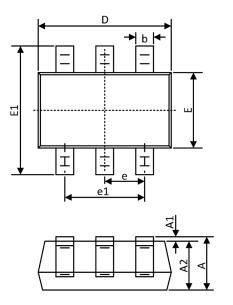
Figure 11. Bandwidth (BW)

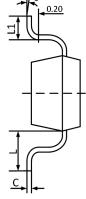




5. Package Information

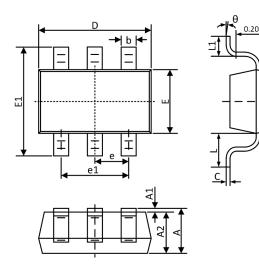
5.1 SOT23-6 (Package Outline Dimensions)





Symbol	1	Dimensions In Millimeters		nsions ches	
	MIN	MAX	MIN	MAX	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.400	0.012	0.016	
с	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
e	0.95	ОТҮР	0.03	7TYP	
e1	1.800	2.000	0.071	0.079	
L	0.70	OREF	0.028REF		
L1	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

5.2 SC70-6 / SOT363 (Package Outline Dimensions)



Symbol		Dimensions In Millimeters		nsions ches	
	MIN	MAX	MIN	MAX	
A	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.150	0.350	0.006	0.014	
с	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
e	0.65	ТҮР	0.026	5 ТҮР	
e1	1.300 BSC		0.051 BSC		
L	0.52	5 REF	0.021 REF		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	